Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN0603-3 (SOT8013) Surface-Mounted Device (SMD) using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Leadless ultra small package 0.63mm x 0.33 mm x 0.25 mm
- · Trench MOSFET technology
- Low profile (0.25 mm)
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- Battery switch
- High-speed line driver
- · Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------|----------------------------------|--|-----|-----|-----|-----|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | - | 30 | V |
| V_{GS} | gate-source voltage |] | | -8 | - | 8 | V |
| I _D | drain current | V _{GS} = 4.5 V; T _{amb} = 25 °C | [1] | - | - | 820 | mA |
| Static charac | teristics | | · | | | | |
| R _{DSon} | drain-source on-state resistance | $V_{GS} = 4.5 \text{ V}; I_D = 1 \text{ A}; T_j = 25 ^{\circ}\text{C}$ | | - | 190 | 250 | mΩ |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 1 cm².



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5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--|----------------|
| 1 | G | gate | | D |
| 2 | S | source | | |
| 3 | D | drain | Transparent top view DFN0603-3 (SOT8013) | G S 017aaa255 |

6. Ordering information

Table 3. Ordering information

| Type number Package | | | | | | | |
|---------------------|------|---|---------|--|--|--|--|
| | Name | Description | Version | | | | |
| PMX300UNE | | DFN0603-3; plastic, ultra small and leadless full encapsulated package; 3 terminals; 0.225 mm pitch; 0.63 mm x 0.33 mm x 0.25 mm body | SOT8013 | | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMX300UNE | Y |

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|---|-----|-----|-----|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | 30 | V |
| V _{GS} | gate-source voltage | | | -8 | 8 | V |
| I _D | drain current | V _{GS} = 4.5 V; T _{amb} = 25 °C | [1] | - | 820 | mA |
| | | V _{GS} = 4.5 V; T _{amb} = 100 °C | [1] | - | 520 | mA |
| I _{DM} | peak drain current | T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$ | | - | 3.3 | Α |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 300 | mW |
| | | | [1] | - | 500 | mW |
| | | T _{sp} = 25 °C | | - | 4.7 | W |
| T _j | junction temperature | | | -55 | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |
| Source-draii | n diode | | | 1 | | , |
| Is | source current | T _{amb} = 25 °C | [1] | - | 0.5 | Α |

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

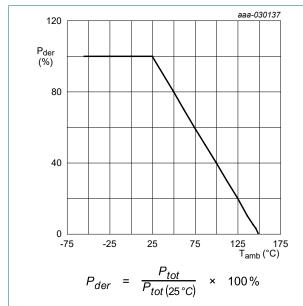


Fig. 1. Normalized total power dissipation as a function of ambient temperature

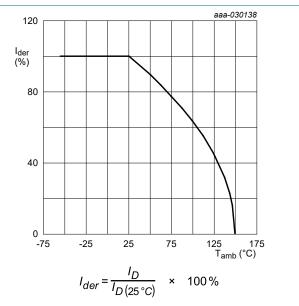


Fig. 2. Normalized continuous drain current as a function of ambient temperature

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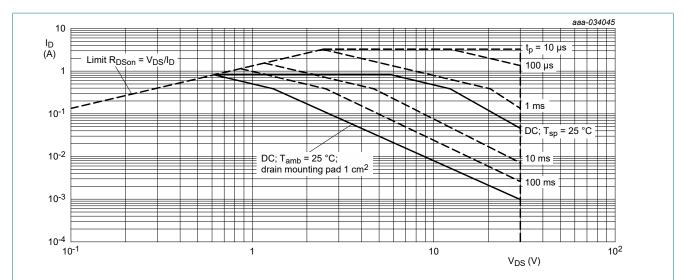


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

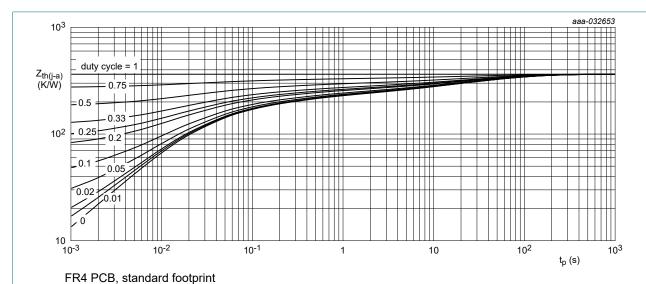
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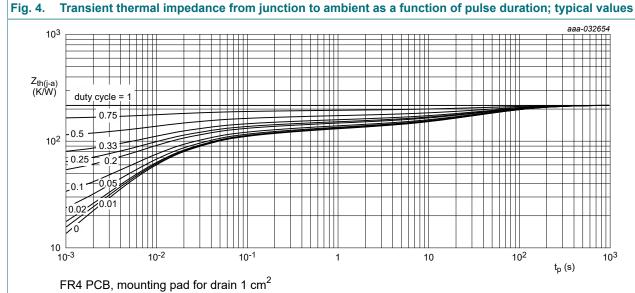
9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|------|------|
| R _{th(j-a)} | thermal resistance from | in free air | [1] | - | 360 | 415 | K/W |
| junction to ambient | | [2] | - | 215 | 250 | K/W | |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | 23 | 26.5 | K/W |

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².





Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-----------------------------------|--|-----|-----|-----|------|
| Static chara | acteristics | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$ | 30 | - | - | V |
| V_{GSth} | gate-source threshold voltage | $I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$ | 0.5 | 0.7 | 0.9 | V |
| I _{DSS} | drain leakage current | $V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | - | 1 | μΑ |
| I _{GSS} | gate leakage current | $V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | - | -10 | μΑ |
| | | V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 10 | μΑ |
| R _{DSon} | drain-source on-state | $V_{GS} = 4.5 \text{ V}; I_D = 1 \text{ A}; T_j = 25 ^{\circ}\text{C}$ | - | 190 | 250 | mΩ |
| resistance | resistance | V _{GS} = 4.5 V; I _D = 1 A; T _j = 150 °C | - | 320 | 420 | mΩ |
| | | $V_{GS} = 2.5 \text{ V}; I_D = 1 \text{ A}; T_j = 25 ^{\circ}\text{C}$ | - | 210 | 330 | mΩ |
| | | V _{GS} = 1.8 V; I _D = 0.5 A; T _j = 25 °C | - | 270 | 750 | mΩ |
| 9 _{fs} | forward transconductance | $V_{DS} = 10 \text{ V}; I_D = 1 \text{ A}; T_j = 25 ^{\circ}\text{C}$ | - | 3.3 | - | S |
| R_{G} | gate resistance | f = 1 MHz | - | 126 | - | Ω |
| Dynamic ch | aracteristics | | • | | | |
| Q _{G(tot)} | total gate charge | V _{DS} = 15 V; I _D = 1 A; V _{GS} = 4.5 V; | - | 1.4 | 2.1 | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | - | 0.2 | - | nC |
| Q_{GD} | gate-drain charge | | - | 0.3 | - | nC |
| C _{iss} | input capacitance | V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V; | - | 120 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 9 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 7 | - | pF |
| t _{d(on)} | turn-on delay time | V _{DS} = 15 V; I _D = 1 A; V _{GS} = 4.5 V; | - | 6 | - | ns |
| t _r | rise time | $R_{G(ext)} = 6 \Omega; T_j = 25 °C$ | - | 8 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 58 | - | ns |
| t _f | fall time | | - | 19 | - | ns |
| Source-drai | in diode | | ' | | | |
| V_{SD} | source-drain voltage | I _S = 0.48 A; V _{GS} = 0 V; T _i = 25 °C | - | 0.8 | 1.2 | V |

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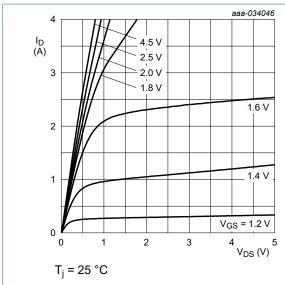


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

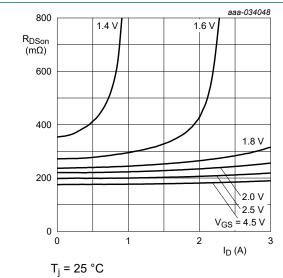


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

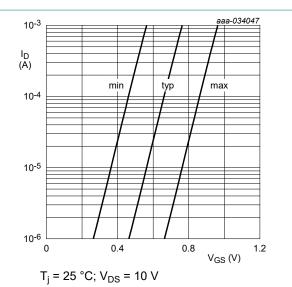


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

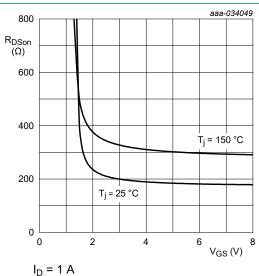


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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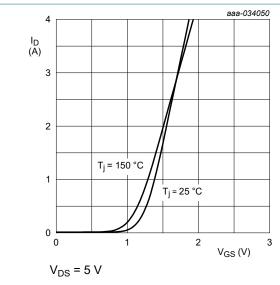


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

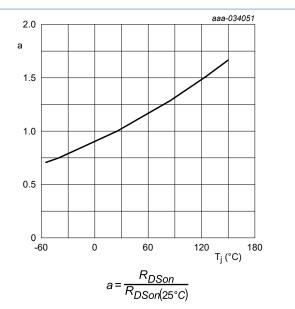


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

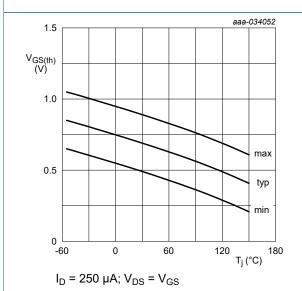
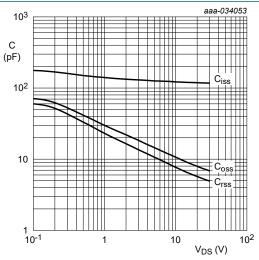


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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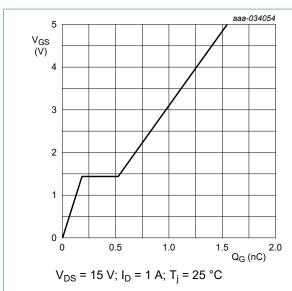


Fig. 14. Gate-source voltage as a function of gate charge; typical values

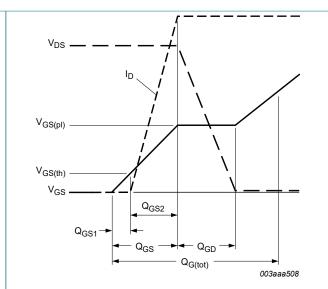


Fig. 15. Gate charge waveform definitions

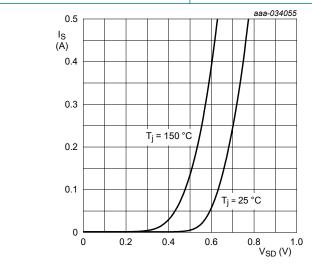
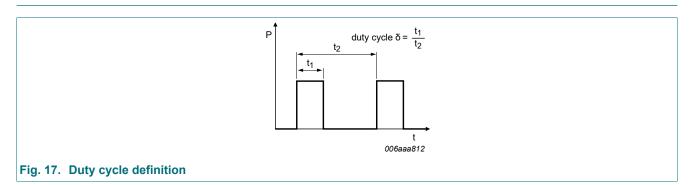


Fig. 16. Source current as a function of source-drain voltage; typical values

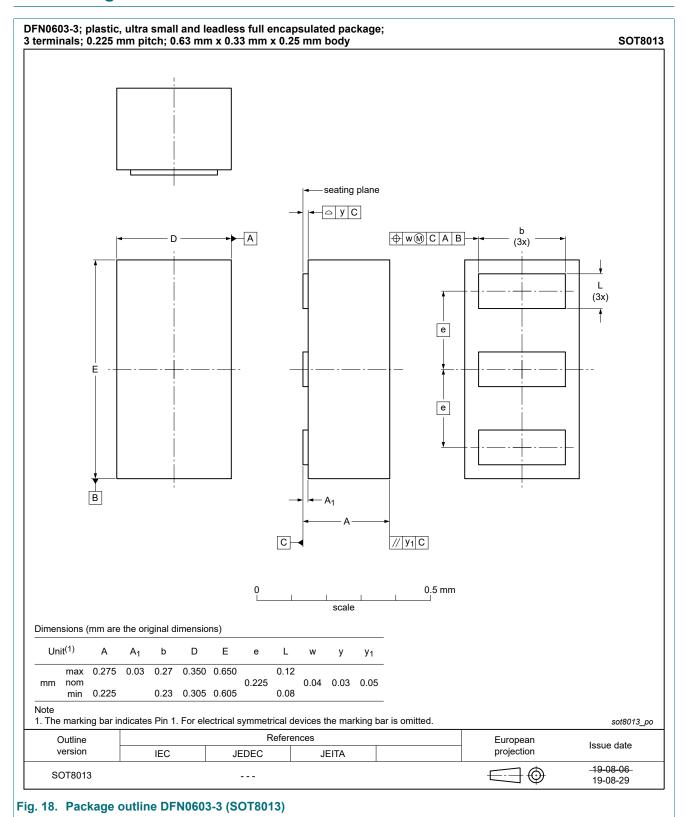
11. Test information

 $V_{GS} = 0 V$



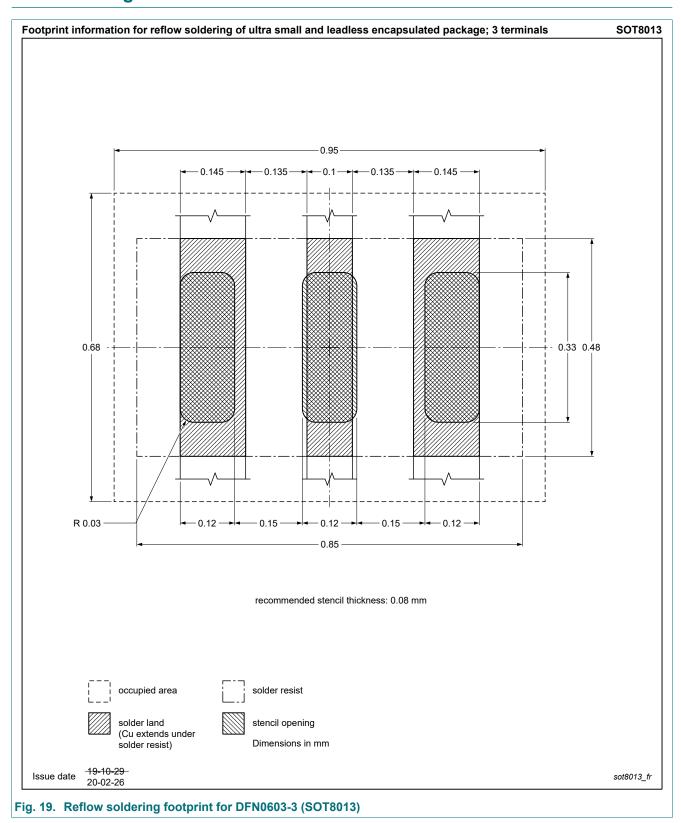
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12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| PMX300UNE v.1 | 20220518 | Product data sheet | - | - |

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15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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